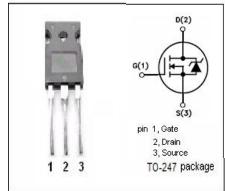
# isc N-Channel MOSFET Transistor

# IRFPE40

#### • FEATURES

- · With TO-247 packaging
- With low gate drive requirements
- · Easy to drive
- 100% avalanche tested
- Minimum Lot-to-Lot variations for robust device performance and reliable operation



### APPLICATIONS

· Switching applications



## • ABSOLUTE MAXIMUM RATINGS(Ta=25°C)

SYMBOL	PARAMETER	METER VALUE	
V <sub>DSS</sub>	Drain-Source Voltage	800	V
V <sub>GSS</sub>	/ <sub>GSS</sub> Gate-Source Voltage		V
I <sub>D</sub>	Drain Current-Continuous @Tc=25℃ Tc=100℃	5.4 3.4	А
I <sub>DM</sub>	Drain Current-Single Pulsed	22	А
P <sub>D</sub>	Total Dissipation	150	W
Tj	Operating Junction Temperature	-55~150	$^{\circ}\mathbb{C}$
T <sub>stg</sub>	Storage Temperature	-55~150	${\mathbb C}$

# mm MAX MIN 19.80 20.20 15.40 15.80 4.90 5.10 0.90 1.40 1.90 G 10.80 Н 2.40 2.60

#### • THERMAL CHARACTERISTICS

SYMBOL	PARAMETER		UNIT	
Rth(ch-c)	Channel-to-case thermal resistance	0.83	°C/W	

J

K

Q

U

0.50

19.50

3.90

3.30

5.20 2.90 20.50

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#### **ELECTRICAL CHARACTERISTICS**

T<sub>C</sub>=25℃ unless otherwise specified

SYMBOL	PARAMETER	CONDITIONS	MIN	TYP	MAX	UNIT
BV <sub>DSS</sub>	Drain-Source Breakdown Voltage	V <sub>GS</sub> =0V; I <sub>D</sub> = 0.25mA	800			V
V <sub>GS</sub> (th)	Gate Threshold Voltage	V <sub>DS</sub> =V <sub>GS</sub> ; I <sub>D</sub> =0.25mA	2.0		4.0	V
R <sub>DS(on)</sub>	Drain-Source On-Resistance	V <sub>GS</sub> = 10V; I <sub>D</sub> =3.2A			2.0	Ω
I <sub>GSS</sub>	Gate-Source Leakage Current	V <sub>GS</sub> = ±20V;V <sub>DS</sub> = 0V			±0.1	μА
I <sub>DSS</sub>	Drain-Source Leakage Current	V <sub>DS</sub> = 800V; V <sub>GS</sub> = 0V;@Tc=25°C V <sub>DS</sub> = 640V; V <sub>GS</sub> = 0V;Tc=125°C			100 500	μА
V <sub>SDF</sub>	Diode forward voltage	I <sub>SD</sub> =5.4A, V <sub>GS</sub> = 0 V			1.8	V



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